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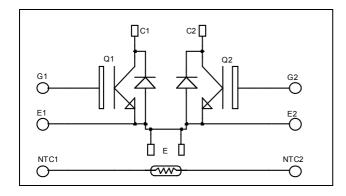








Dual common source Trench + Field Stop IGBT3 Power Module



G2 #

E2 f

E2 f

G2 f

 $V_{CES} = 600V$ $I_{C} = 200A$ @ $T_{C} = 80^{\circ}C$

Application

- AC Switches
- Switched Mode Power Supplies
- Uninterruptible Power Supplies

Features

- Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- High level of integration
- Internal thermistor for temperature monitoring



- Stable temperature behavior
- Very rugged
- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		600	V
I_{C}	Continuous Collector Current	$T_C = 25^{\circ}C$	290	
1C	Continuous Conector Current	$T_C = 80$ °C	200	A
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	400	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25$ °C	625	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150$ °C	400A @ 550V	

C2

C2

NTC2 #

NTC1 #

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 600V$				250	μΑ
V	Collector Emitter Saturation Voltage	$V_{GE} = 15V$			1.5	1.9	V
V _{CE(sat)}	Conector Emitter Saturation Voltage	$I_{\rm C} = 200 {\rm A}$ $T_{\rm j} = 150 {\rm ^{\circ}C}$		1.7		·	
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 2 \text{ mA}$		5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} =$	= 0V			400	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$			12.3		
C_{oes}	Output Capacitance	$V_{CE} = 25V$			0.8		nF
C_{res}	Reverse Transfer Capacitance	f = 1MHz			0.4		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch	ning (25°C)		115		
T_{r}	Rise Time	$V_{GE} = \pm 15V$			45		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 300V$ $I_{C} = 200A$			225		ns
T_{f}	Fall Time	$R_G = 2\Omega$			55		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch	ning (150°C)		130		
T_{r}	Rise Time	$V_{GE} = \pm 15V$			50		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 300V$ $I_{C} = 200A$			300		ns
T_{f}	Fall Time	$R_G = 2\Omega$			70		
Б	Turn on Engrav	$V_{GE} = \pm 15V$	$T_j = 25$ °C		1		ma I
Eon	Turn on Energy	$V_{\text{Bus}} = 300\text{V}$	$T_{\rm j} = 150^{\circ}{\rm C}$		1.8		mJ
Е	Turn off Energy	$I_{\rm C} = 200 {\rm A}$	$T_j = 25$ °C		5.7		m I
E_{off}	Turn off Energy	$R_G = 2\Omega$	$T_{\rm j} = 150^{\circ}{\rm C}$		7		mJ

Reverse diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit	
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			600			V	
I_{RM}	Maximum Reverse Leakage Current	V _R =600V	$T_i = 25^{\circ}C$ $T_i = 150^{\circ}C$			250 500	μΑ	
I_{F}	DC Forward Current		$Tc = 80^{\circ}C$		200		A	
V_{F}	Diode Forward Voltage	$I_F = 200A$	$T_i = 25^{\circ}C$		1.6	2	V	
v _F	Diode Forward Voltage	$V_{GE} = 0V$	$T_{i} = 150^{\circ}C$		1.5		v	
+	Reverse Recovery Time		$T_j = 25$ °C		130		ns	
t_{rr}	·	$T_i = 150^{\circ}$	$T_{\rm j} = 150^{\circ}{\rm C}$		225		115	
	Daviana Dagayany Changa	$I_F = 200A$ $V_R = 300V$	$T_j = 25$ °C		9		C	
Q_{rr}	Reverse Recovery Charge	Reverse Recovery Charge $\frac{V_R - 300V}{\text{di/dt} = 2200\text{A/}\mu\text{s}}$		$T_{\rm j} = 150^{\circ}{\rm C}$		19		μС
Er	Davarga Dagayary Engray	απαι 220011/μο	$T_j = 25$ °C		2.3		mJ	
EI	Reverse Recovery Energy		$T_{i} = 150^{\circ}C$		4.7		1113	



Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Тур	Max	Unit	
R ₂₅	Resistance @ 25°C		50		kΩ	
${ m B}_{25/85}$	$T_{25} = 298.15 \text{ K}$		3952		K	

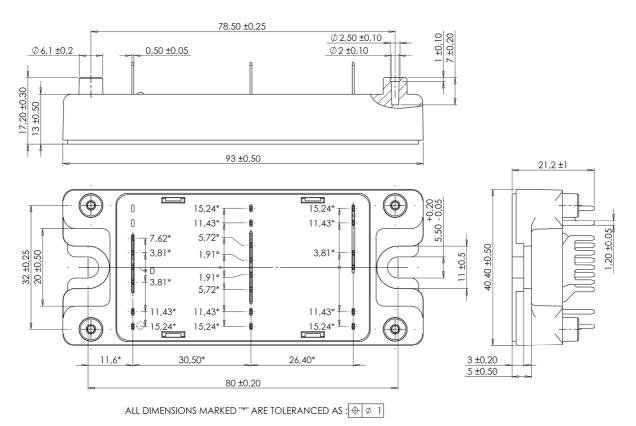
$$R_T = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$

$$R_T: \text{ Thermistor value at T}$$

Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	R _{thIC} Junction to Case Thermal Resistance		IGBT			0.24	°C/W
TthJC	Junetion to Case Thermal Resistance		Diode			0.4	C/ W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =	l min, 50/60Hz		4000			V
T_{J}	Operating junction temperature range			-40		175	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To Heatsink	M5	2.5		4.7	N.m
Wt	Package Weight					160	g

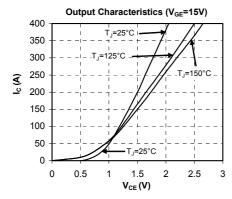
SP4 Package outline (dimensions in mm)

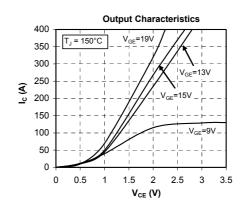


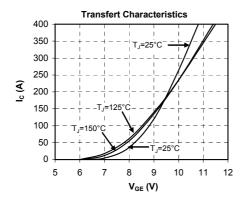
See application note APT0501 - Mounting Instructions for SP4 Power Modules on www.microsemi.com

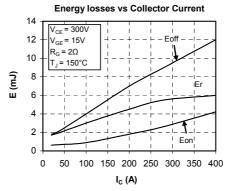


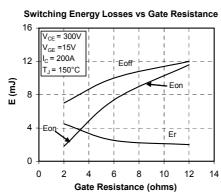
Typical Performance Curve

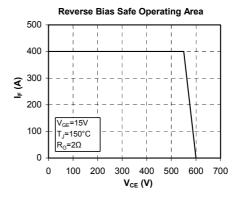


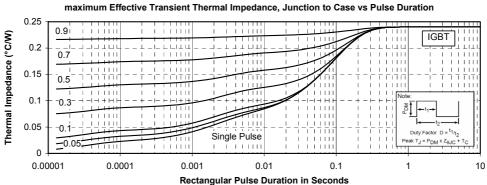




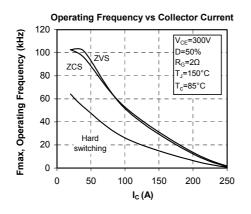


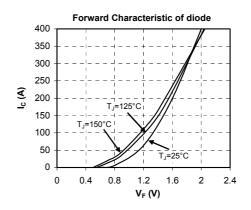


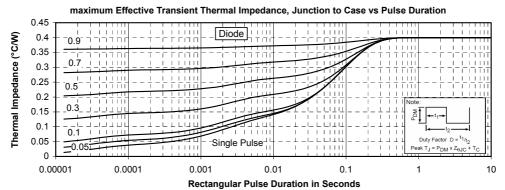














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